

Hyperfast Rectifier, 30 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES





PRIMARY CHARACTERISTICS						
I _{F(AV)} 30 A						
V_{R}	600 V					
V _F at I _F at 125 °C	1.3 V					
T _J max.	175 °C					
t _{rr} (typ.)	22 ns					
Package	D ² PAK 2L (TO-263AB 2L)					
Circuit configuration	Single					

FEATURES

 Best in class forward voltage drop and switching losses trade off



· Optimized for high speed operation

175 °C maximum operating junction temperature

ROHS COMPLIANT HALOGEN FREE

Polyimide passivation

• AEC-Q101 qualified, meets JESD 201 class 2 whisker test

- Meets MSL level, per J-Std-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Repetitive peak reverse voltage	V_{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 106 °C, D = 0.50	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	310	Α			
Repetitive peak forward current	I _{FRM}	T _C = 106 °C, D = 0.50, f = 20 kHz	60				
Operating junction and storage temperature	T _J , T _{Stq}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	600	-	-	.,		
Forward voltage	V _F	I _F = 30 A	-	1.6	2.1	V		
		I _F = 30 A, T _J = 125 °C	-	1.3	-			
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	20			
neverse leakage current		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	500	μA		
Junction capacitance	C _T	V _R = 200 V	-	36	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		





DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A,dI _F /dt = 100 A/μs, V _R = 30 V		-	22	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	39	-	ns	
		T _J = 125 °C		-	50	-	1	
Peak recovery current		$I_F = 20 \text{ A}$	-	14	=	Α		
Feak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 1000 A/μs - V _R = 400 V	-	24	-] ^	
Boyerea receivent charge	Q _{rr}	T _J = 25 °C		-	253	-	nC	
Reverse recovery charge		T _J = 125 °C		-	785	=		
Boyerea receivery time		T _J = 25 °C	I _F = 30 A dI _F /dt = 1000 A/µs · V _R = 400 V	-	41	=	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	56	=		
Dook receiver augrent		T _J = 25 °C		-	16	=	А	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	27	=		
D		T _J = 25 °C		-	306	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	952	-		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.3	°C/W		
Weight			-	2.0	-	g		
			-	0.07	-	OZ.		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Marking device		Case style: D ² PAK 2L (TO-263AB 2L)	E5TX3006SH					



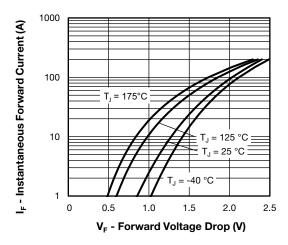


Fig. 1 - Typical Forward Voltage Drop Characteristics

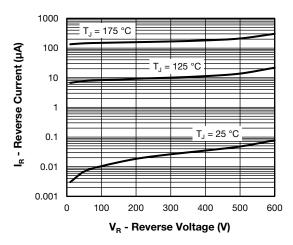


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

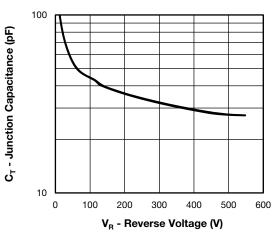


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

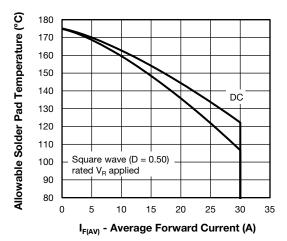


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

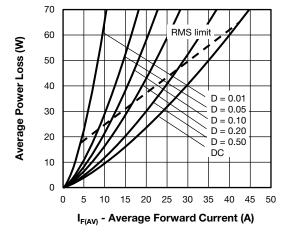


Fig. 5 - Average Power Loss vs. Average Forward Current

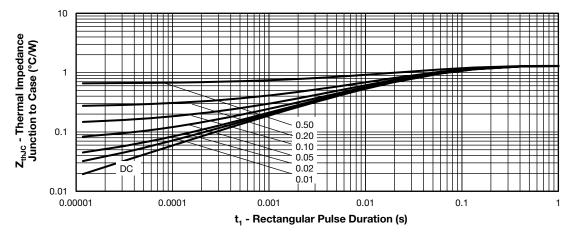


Fig. 6 - Thermal Impedance Z_{thJC} - Characteristics

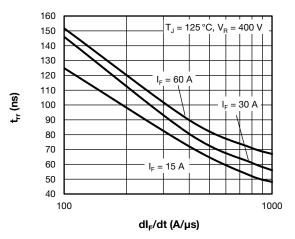


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

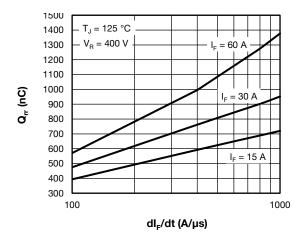


Fig. 8 - Typical Reverse Recovery Charge vs. dI_F/dt

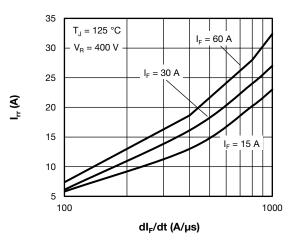


Fig. 9 - Typical Reverse Recovery Current vs. dI_F/dt

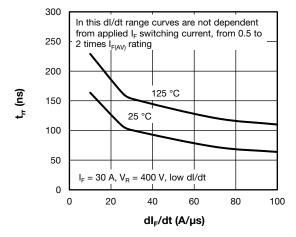
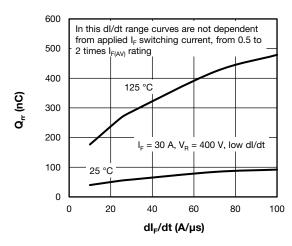


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt





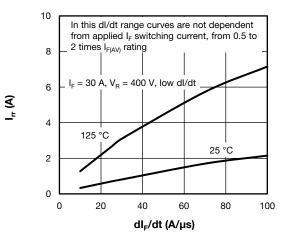


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

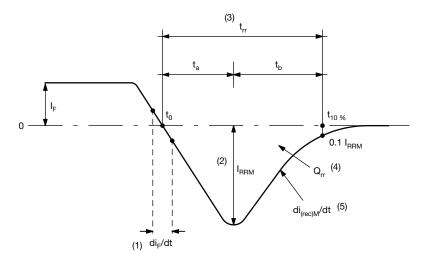


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM} $^{(4)}$ Q_{rr} area under curve defined by t_0 and $t_{10\%}$

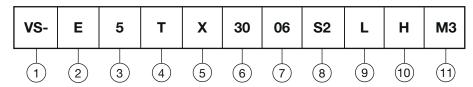
$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - E = single diode

3 - 5 = FRED generation 5

4 - Package:

 $T = D^2PAK$ (TO-262) package

5 - X = hyperfast recovery

6 - Current rating (30 = 30 A)

7 - Voltage rating (06 = 600 V)

8 - S2 = true 2 pin D^2PAK

9 - None = tube (50 pieces)

• L = tape and reel (left oriented, for D²PAK package)

If needed different orientation/packaging, please contact factory

10 - H = AEC-Q101 qualified

11 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION							
VS-E5TX3006S2LHM3	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96683
Part marking information	www.vishay.com/doc?96693
Packaging information	www.vishay.com/doc?95032
SPICE model	www.vishay.com/doc?96918



D²PAK 2L (TO-263AB 2L)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS INCHES		NOTES			
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625		
L	1.78	2.79	0.070	0.110		
L1	-	1.65	-	0.066	3	
L3	0.25 BSC		0.010	BSC		
L4	4.78	5.28	0.188	0.208		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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